Data sheet acquired from Harris Semiconductor SCHS193A

January 1998 - Revised May 2003

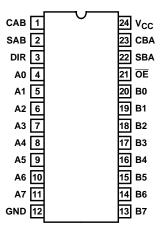
NOT RECOMMENDED FOR NEW DESIGNS **High-Speed CMOS Logic** Octal Bus Transceiver/Register, Three-State

Features

- · Independent Registers for A and B Buses
- Non-Inverting
- · Three-State Outputs
- Drives 15 LSTTL Loads
- Typical Propagation Delay = 12ns (A to B, B to A) at $V_{CC} = 5V, C_1 = 15pF, T_{\Delta} = 25^{\circ}C$
- Fanout (Over Temperature Range)
 - Standard Outputs........... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at $V_{CC} = 5V$

Pinout

CD74HC646 (SOIC) TOP VIEW



Description

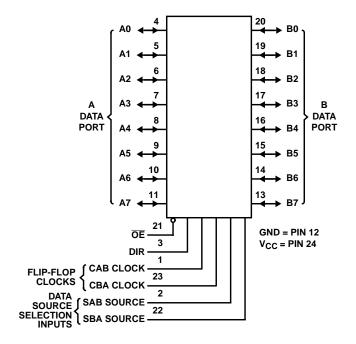
The CD74HC646 is an octal bus transceiver/register with three-state non-inverting outputs. This device is a bus transceiver with D-type flip-flops which act as internal storage registers. Data on the A bus or the B bus can be clocked into the registers on the Low-to-High transition of either CAB or CBA clock inputs. Outputs enable (OE) and direction (DIR) inputs control the transceiver functions. Data present at the high impedance output can be stored in either register or both but only one of the two buses can be enabled as outputs at any one time. The select controls (SAB and SBA) can multiplex stored and transparent (real time) data. The direction control determines which data bus will receive data when the output enable (OE) is Low. In the high impedance mode (output enable High), A data can be stored in one register and B data can be stored in the other register. The clocks are not gated with the direction (DIR) and output enable (OE) terminals: data at the A or B terminals can be clocked into the storage flip-flops at any time.

Ordering Information

PART NUMBER	TEMP. RANGE (^O C)	PACKAGE
CD74HC646M	-55 to 125	24 Ld SOIC
CD74HC646M96	-55 to 125	24 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

Functional Diagram



FUNCTION TABLE

		INP	UTS			DATA I/O	(NOTE 1)	
ŌĒ	DIR	CAB	СВА	SAB	SBA	A0 THRU A7	B0 THRU B7	OPERATION OR FUNCTION
Х	Х	1	Х	Х	Х	Input	Not Specified	Store A, B Unspecified
Х	Х	Х	↑	Х	Х	Not Specified	Input	Store B, A Unspecified
Н	Х	1	1	Х	Х	Input	Input	Store A and B Data
Н	Х	H or L	H or L	Х	Х			Isolation, Hold Storage
L	L	Х	Х	Х	L	Output	Input	Real-Time B Data to A Bus
L	L	Х	H or L	Х	Н			Stored B Data to A Bus
L	Н	Х	Х	L	Х	Input	Output	Real-Time A Data to B Bus
L	Н	H or L	Х	Н	Х			Stored A Data to B Bus

NOTE:

The data output functions may be enabled or disabled by various signals at the OE and DIR inputs. Data inputs functions
are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs. To prevent
excess currents in the High-Z modes all I/O terminals should be terminated with 10kΩ resistors.

CD74HC646

Absolute Maximum Ratings

DC Supply Voltage, V $_{CC}$... -0.5V to 7V DC Input Diode Current, I $_{IK}$ For V $_{I}$ < -0.5V or V $_{I}$ > V $_{CC}$ + 0.5V ± 20 mA DC Output Diode Current, I $_{OK}$ For V $_{O}$ < -0.5V or V $_{O}$ > V $_{CC}$ + 0.5V ± 20 mA DC Drain Current, per Output, I $_{O}$ For -0.5V < V $_{O}$ < V $_{CC}$ + 0.5V ± 35 mA DC Output Source or Sink Current per Output Pin, I $_{O}$ For V $_{O}$ > -0.5V or V $_{O}$ < V $_{CC}$ + 0.5V ± 25 mA DC V $_{CC}$ or Ground Current, I $_{CC}$... ± 50 mA

Thermal Information

Thermal Resistance (Typical)	θ _{JA} (°C/W)
M (SOIC) Package (Note 2)	. 46
Maximum Junction Temperature	
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range, T _A
Supply Voltage Range, V _{CC}
HC Types2V to 6V
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			TEST CONDITIONS			25°C		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
CIVIOS LOAGS			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
TTL LOads			-7.8	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
CIVIOS LOADS			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
TTL LOads			7.8	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	Ι _Ι	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ
Three-State Leakage Current	loz	V _{IL} or V _{IH}	V _O = V _{CC} or GND	6	-	-	±0.5	-	±5	-	±10	μΑ

CD74HC646

Prerequisite for Switching Specifications

				25°C		-40°C TO 85°C			-55°C TO 125°C			
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
HC TYPES		-										
Maximum Frequency	f _{MAX}	2	6	-	-	5	-	-	4	-	-	MHz
		4.5	30	-	-	25	-	-	20	-	-	MHz
		6	35	-	-	29	-	-	23	-	-	MHz
Setup Time Data to Clock	tsu	2	60	-	-	75	-	-	90	-	-	ns
		4.5	12	-	-	15	-	-	18	-	-	ns
		6	10	-	-	13	-	-	15	-	-	ns
Hold Time Data to Clock	t _H	2	35	-	-	45	-	-	55	-	-	ns
		4.5	7	-	-	9	-	-	11	-	-	ns
		6	6	-	-	8	-	-	9	-	-	ns
Clock Pulse Width	t _W	2	80	-	-	100	-	-	120	-	-	ns
		4.5	16	-	-	20	-	-	24	-	-	ns
		6	14	-	-	17	-	-	20	-	-	ns

Switching Specifications $C_L = 50 pF$, Input t_f , $t_f = 6 ns$

		TEST		25°C			-40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES	·											
Propagation Delay Store A Data to B Bus	t _{PHL} , t _{PLH}	C _L = 50pF	2	-	-	220	-	275	-	330	ns	
Store B Data to B Bus			4.5	-	-	44	-	55	-	66	ns	
		C _L = 15pF	5	-	18	-	-	-	=	-	ns	
		C _L = 50pF	6	-	-	37	-	47	-	56	ns	
A Data to B Bus	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	135	-	170	-	205	ns	
B Data to A Bus			4.5	-	-	27	-	34	-	41	ns	
		C _L = 15pF	5	-	12	-	-	-	-	-	ns	
		C _L = 50pF	6	-	-	23	-	29	-	35	ns	
Select to Data	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	170	-	215	-	255	ns	
			4.5	-	-	34	-	43	-	51	ns	
		C _L = 15pF	5	-	14	-	-	-	-	-	ns	
		C _L = 50pF	6	-	-	29	-	37	-	43	ns	

CD74HC646

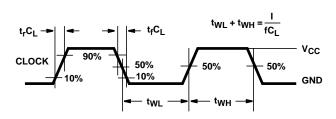
Switching Specifications $C_L = 50 pF$, Input t_f , $t_f = 6 ns$ (Continued)

		TEST			25°C			C TO °C		C TO 5°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Three-State Disabling Time Bus to Output or Register to	t _{PLZ} , t _{PHZ}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
Output Of Register to			4.5	-	-	35	-	44	-	53	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Three-State Enabling Time Bus to Output or Register to	t _{PZL} , t _{PZH}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
Output Output			4.5	-	-	35	-	44	-	53	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	60	-	75	-	90	ns
			4.5	-	-	12	-	15	-	18	ns
		C _L = 50pF	6	-	-	10	-	13	-	15	ns
Input Capacitance	C _{IN}	C _L = 50pF	-	10	-	10	-	10	-	10	pF
Three-State Output Capacitance	CO	-	-	-	-	20	-	20	-	20	pF
Maximum Frequency	f _{MAX}	C _L = 15pF	5	-	60	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	52	-	-	-	-	-	pF

NOTES:

- 3. C_{PD} is used to determine the dynamic power consumption, per package.
 4. P_D = V_{CC}² C_{PD} f_i ∑ V_{CC}² C_L f_o where f_i = Input Frequency, f_o = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

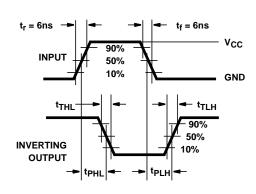


FIGURE 2. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

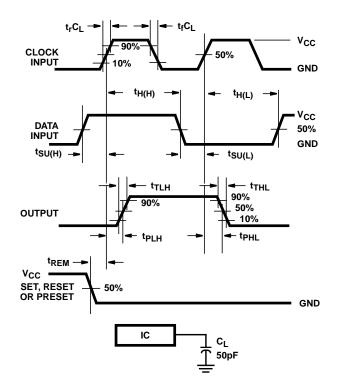


FIGURE 3. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

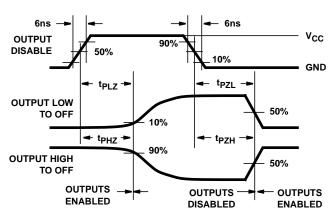
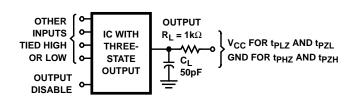


FIGURE 4. HC THREE-STATE PROPAGATION DELAY WAVEFORM



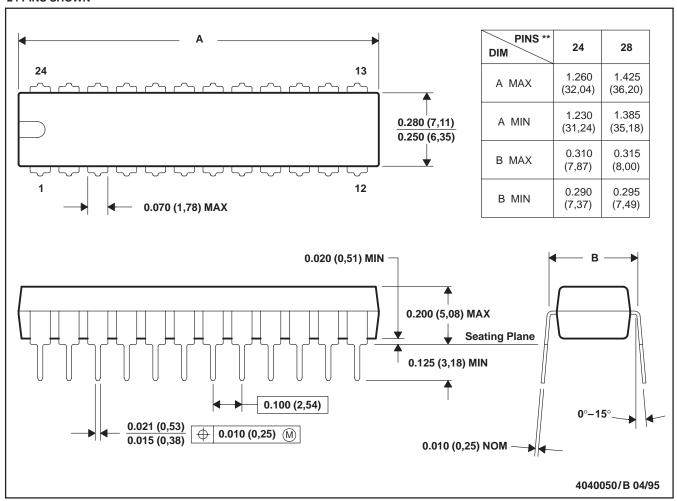
NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 5. HC THREE-STATE PROPAGATION DELAY TEST CIRCUIT

NT (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

24 PINS SHOWN

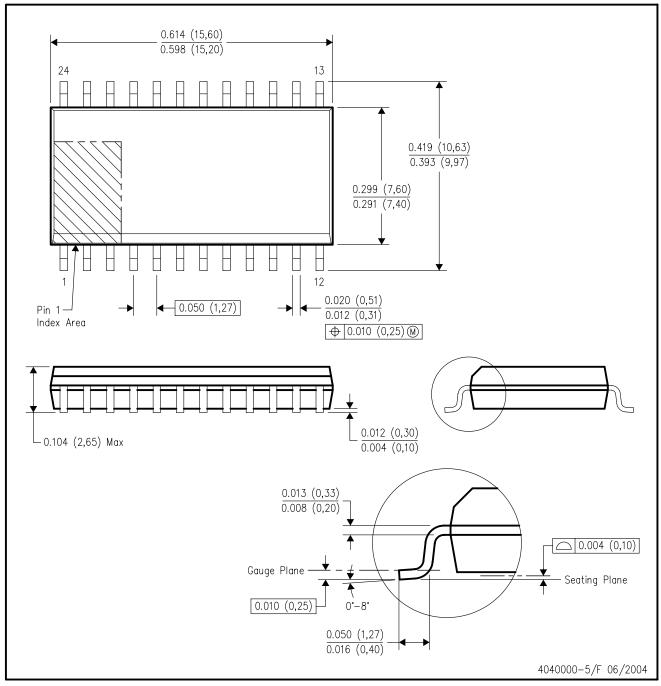


NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

DW (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



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